



STTH6003TV/CW

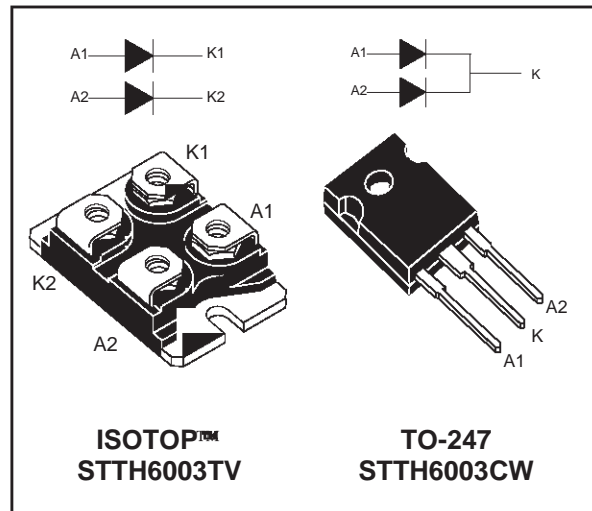
HIGH FREQUENCY SECONDARY RECTIFIER

MAJOR PRODUCT CHARACTERISTICS

$I_{F(AV)}$	2 x 30 A
V_{RRM}	300 V
$V_F(max)$	1 V
$t_{rr}(max)$	55 ns

FEATURES AND BENEFITS

- COMBINES HIGHEST RECOVERY AND VOLTAGE PERFORMANCE
- ULTRA-FAST, SOFT AND NOISE-FREE RECOVERY
- INSULATED PACKAGE: ISOTOP
Insulation voltage: 2500 V_{RMS}
Capacitance: < 45 pF
- LOW INDUCTANCE AND LOW CAPACITANCE ALLOW SIMPLIFIED LAYOUT



DESCRIPTION

Dual rectifiers suited for Switch Mode Power Supply and high frequency DC to DC converters.

Packaged either in ISOTOP or in TO-247, this device is intended for use in low voltage, high

frequency inverters, free wheeling operation, welding equipments and telecom power supplies.

ABSOLUTE RATINGS (limiting values, per diode)

Symbol	Parameter			Value	Unit	
V_{RRM}	Repetitive peak reverse voltage			300	V	
$I_{F(RMS)}$	RMS forward current		ISOTOP	100	A	
$I_{F(RMS)}$	RMS forward current		TO-247	60	A	
$I_{F(AV)}$	Average forward current	ISOTOP	$T_c = 95^\circ\text{C}$ $\delta = 0.5$	Per diode Per device	30 60	A
		TO-247	$T_c = 135^\circ\text{C}$ $\delta = 0.5$	Per diode Per device	30 60	A
I_{FSM}	Surge non repetitive forward current.	ISOTOP	$t_p = 10$ ms sinusoidal		400	A
		TO-247	$t_p = 10$ ms sinusoidal		300	A
I_{RSM}	Non repetitive peak reverse current		$t_p = 100$ μs square		4	A
T_{stg}	Storage temperature range	ISOTOP			- 55 to + 150	$^\circ\text{C}$
		TO-247			- 65 to + 175	$^\circ\text{C}$
T_j	Maximum operating junction temperature	ISOTOP			150	$^\circ\text{C}$
		TO-247			175	$^\circ\text{C}$

THERMAL RESISTANCES

Symbol	Parameter			Value	Unit
R _{th(j-c)}	Junction to case	ISOTOP	Per diode Total	1.4 0.75	°C/W
		TO-247	Per diode Total	1 0.55	
R _{th(c)}			Coupling	0.1	

When the diodes 1 and 2 are used simultaneously:

$$\Delta T_j (\text{diode 1}) = P (\text{diode 1}) \times R_{th(j-c)} (\text{per diode}) + P (\text{diode 2}) \times R_{th(c)}$$

STATIC ELECTRICAL CHARACTERISTICS (per diode)

Symbol	Parameter	Tests conditions		Min.	Typ.	Max.	Unit
I _R *	Reverse leakage current	V _R = 300 V	T _j = 25°C			60	μA
			T _j = 125°C		60	600	
V _F **	Forward voltage drop	I _F = 30 A	T _j = 25°C			1.25	V
			T _j = 125°C		0.85	1	

Pulse test : * t_p = 5 ms, δ < 2 %

** t_p = 380 μs, δ < 2%

To evaluate the maximum conduction losses use the following equation:

$$P = 0.75 \times I_{F(AV)} + 0.008 \times I_{F(RMS)}^2$$

RECOVERY CHARACTERISTICS

Symbol	Tests conditions			Min.	Typ.	Max.	Unit
trr	I _F = 0.5 A	I _{rr} = 0.25 A	I _R = 1 A	T _j = 25°C		40	ns
	I _F = 1 A	dI _F /dt = - 50 A/μs	V _R = 30 V			55	
tfr	I _F = 30 A	dI _F /dt = 200 A/μs		T _j = 25°C		350	ns
V _{FP}	V _{FR} = 1.1 x V _F max.					5	V
S _{factor}	V _{CC} = 200 V	I _F = 30 A		T _j = 125°C		0.3	-
I _{RM}	dI _F /dt = 200 A/μs						11

Fig. 1: Conduction losses versus average current (per diode).

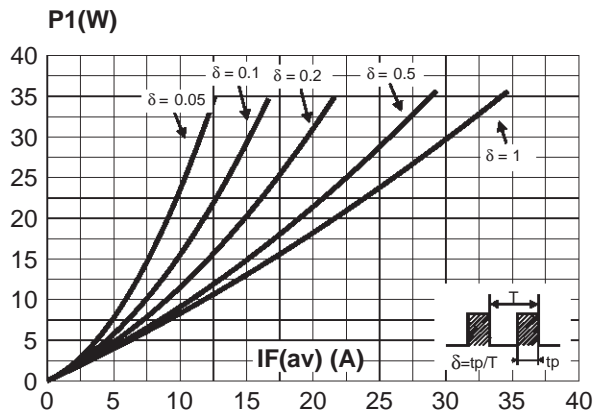


Fig. 2: Forward voltage drop versus forward current (maximum values, per diode).

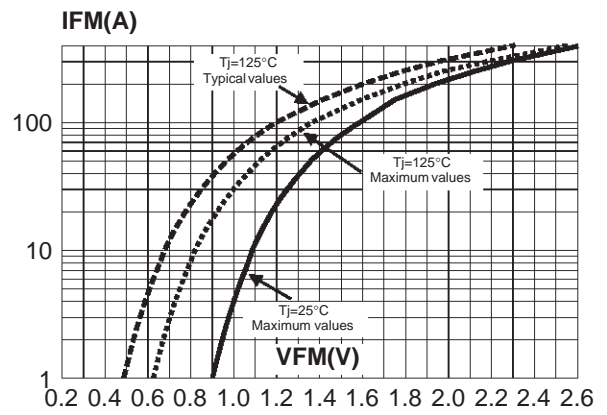


Fig. 3a: Relative variation of thermal impedance junction to case versus pulse duration (ISOTOP).

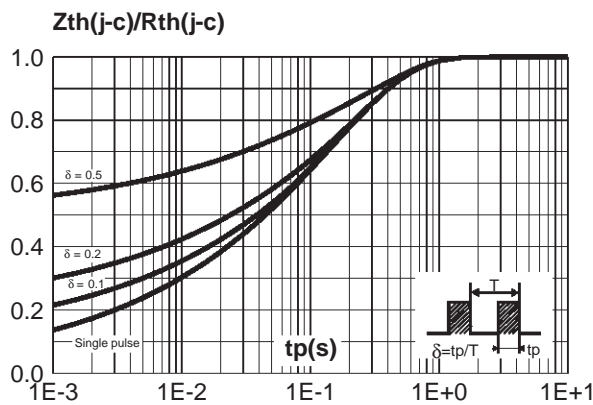


Fig. 3b: Relative variation of thermal impedance junction to case versus pulse duration (TO-247).

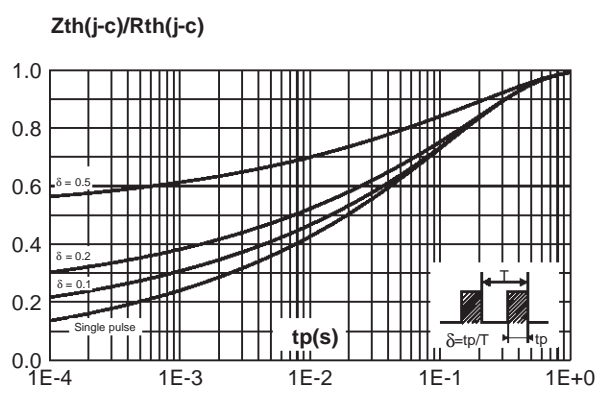


Fig. 4: Peak reverse recovery current versus dIF/dt (90% confidence, per diode).

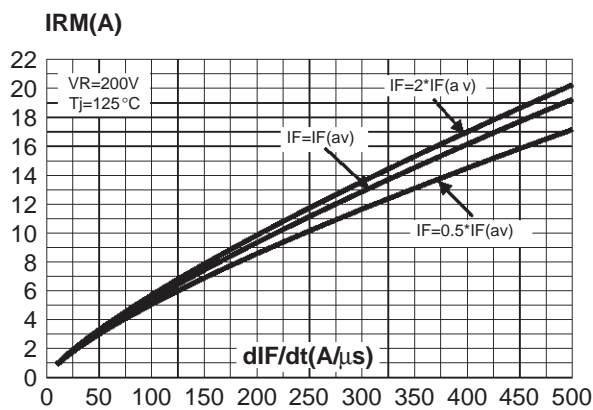


Fig. 5: Reverse recovery time versus dIF/dt (90% confidence, per diode).

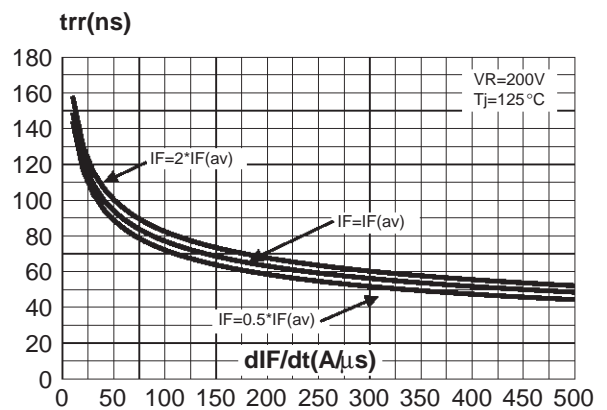


Fig. 6: Softness factor (tb/ta) versus dI_F/dt (typical values, per diode).

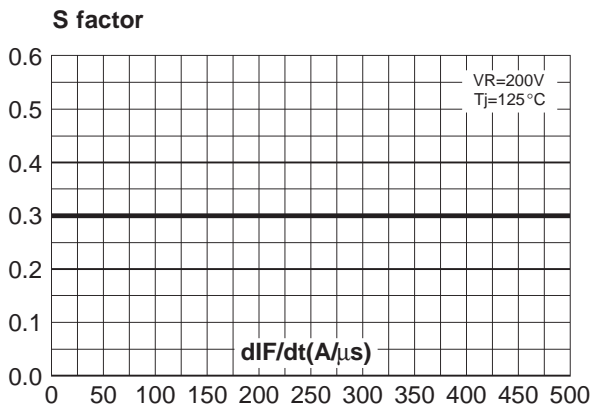


Fig. 7: Relative variation of dynamic parameters versus junction temperature (reference: $T_j = 125^\circ\text{C}$).

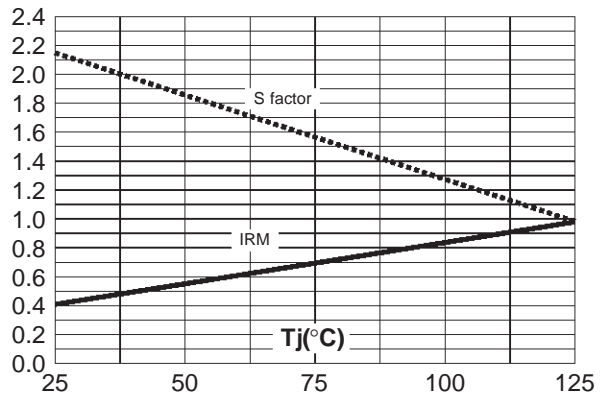


Fig. 8: Transient peak forward voltage versus dI_F/dt (90% confidence, per diode).

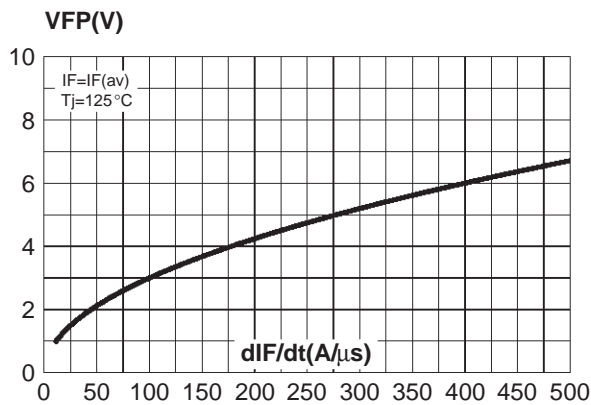
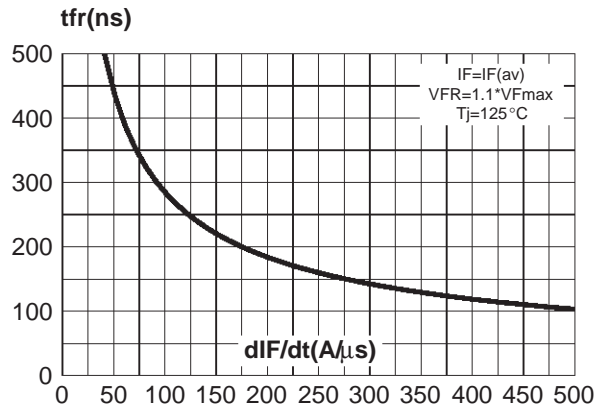
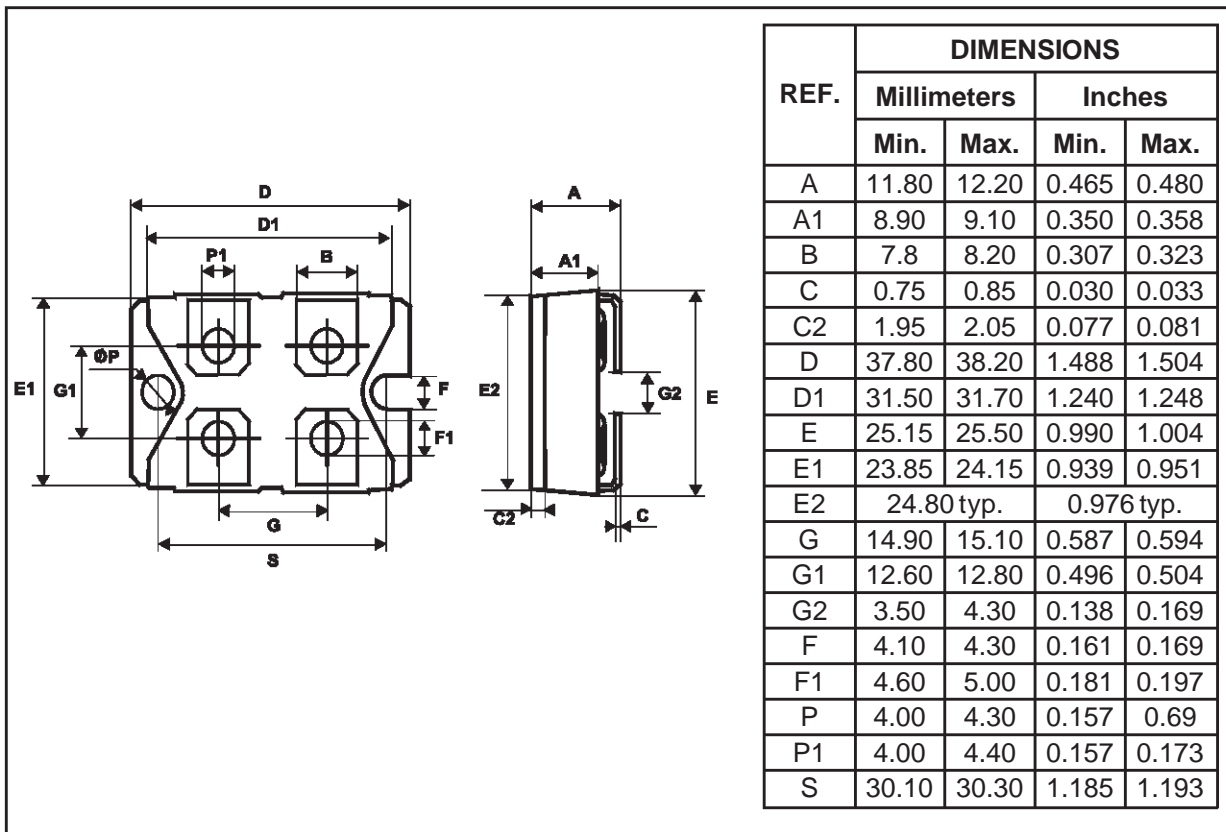


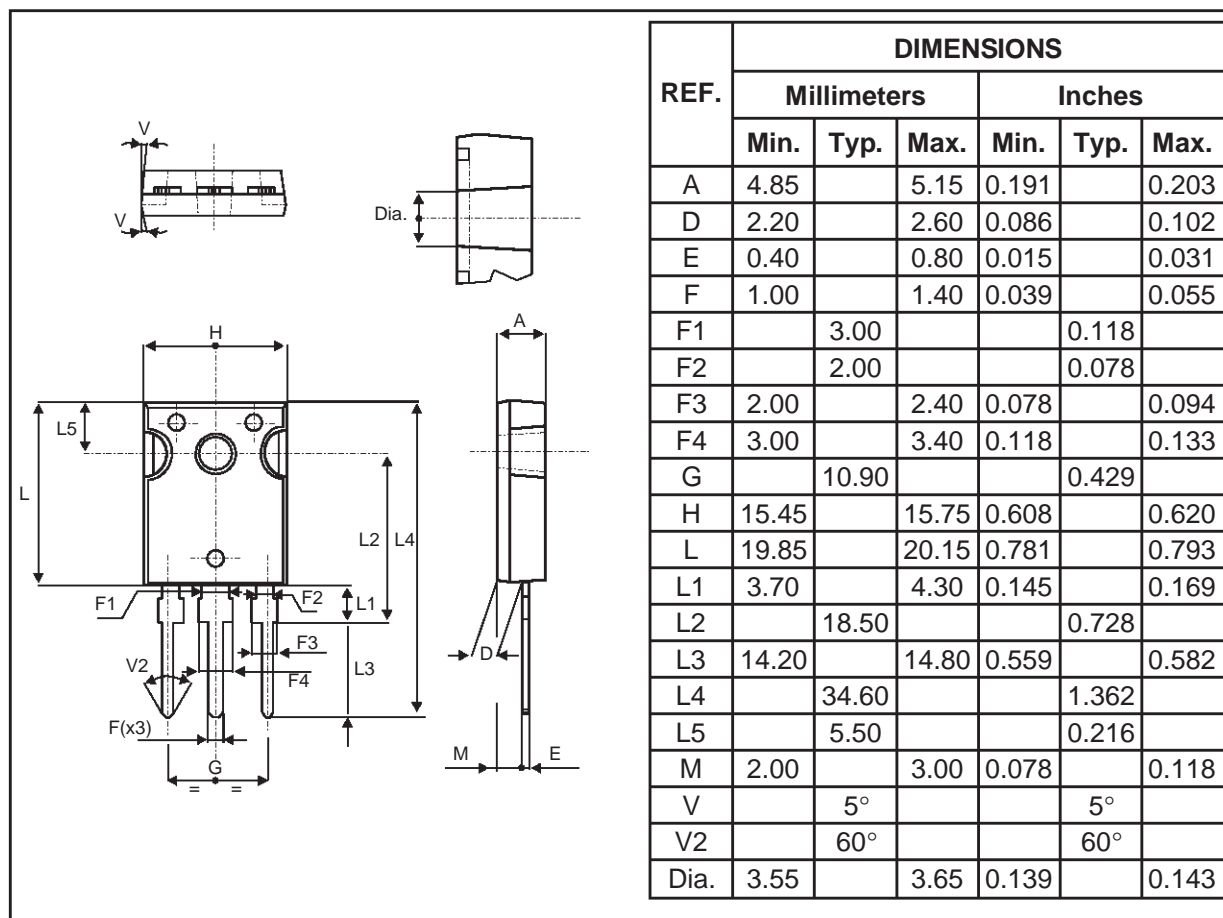
Fig. 9: Forward recovery time versus dI_F/dt (90% confidence, per diode).



PACKAGE MECHANICAL DATA
ISOTOP



PACKAGE MECHANICAL DATA
TO-247



Ordering code	Marking	Package	Weight	Base qty	Delivery mode
STTH6006TV1	STTH6006TV	ISOTOP	27g without screws	10 with screws	Tube
STTH6006CW	STTH6006CW	TO-247	4.36g	30	Tube

- Cooling method: by conduction (C)
- Recommended torque value (ISOTOP): 1.3 N.m.
- Recommended torque value (TO-247°): 0.8 N.m.
- Maximum torque value (ISOTOP): 1.5 N.m.
- Maximum torque value (TO-247): 1.0 N.m.
- Epoxy meets UL 94, V0

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